

NJD1718, NJVNJD1718

Power Transistors

PNP Silicon DPAK For Surface Mount Applications

Designed for high-gain audio amplifier and power switching applications.

Features

- Low Collector-Emitter Saturation Voltage
- High Switching Speed
- Epoxy Meets UL 94 V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Base Voltage	V_{CB}	-50	Vdc
Collector-Emitter Voltage	V_{CEO}	-50	Vdc
Emitter-Base Voltage	V_{EB}	-5	Vdc
Collector Current - Continuous	I_C	-2	Adc
Collector Current - Peak	I_{CM}	-3	Adc
Base Current	I_B	-0.4	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	15 0.1	W W/ $^\circ\text{C}$
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ (Note 1) Derate above 25°C	P_D	1.68 0.011	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
ESD - Human Body Model	HBM	3B	V
ESD - Machine Model	MM	C	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction-to-Case Junction-to-Ambient (Note 2)	$R_{\theta JC}$ $R_{\theta JA}$	10 89.3	$^\circ\text{C/W}$

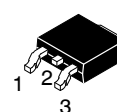
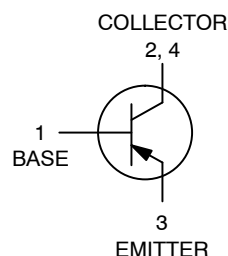
2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.



ON Semiconductor®

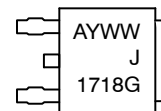
<http://onsemi.com>

SILICON POWER TRANSISTORS 2 AMPERES 50 VOLTS 15 WATTS



DPAK
CASE 369C
STYLE 1

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Device

ORDERING INFORMATION

Device	Package	Shipping [†]
NJD1718T4G	DPAK (Pb-Free)	2500 / Tape & Reel
NJVNJD1718T4G	DPAK (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NJD1718, NJVNJD1718

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage (Note 3) ($I_C = -10\text{ mAdc}$, $I_B = 0$)	BV_{CEO}	-50		-	Vdc
Collector Cutoff Current ($V_{CB} = -50\text{ Vdc}$, $I_E = 0$)	I_{CBO}	-		-100	nAdc
Emitter Cutoff Current ($V_{BE} = -5\text{ Vdc}$, $I_C = 0$)	I_{EBO}	-		-100	nAdc

ON CHARACTERISTICS

DC Current Gain (Note 3) ($I_C = -0.5\text{ A}$, $V_{CE} = 2\text{ V}$) ($I_C = -1.5\text{ Adc}$, $V_{CE} = 2\text{ Vdc}$)	h_{FE}	70 40		240 -	-
Collector-Emitter Saturation Voltage (Note 3) ($I_C = -1\text{ A}$, $I_B = -0.05\text{ A}$)	$V_{CE(sat)}$	-	-0.2	-0.5	Vdc
Base-Emitter Saturation Voltage (Note 3) ($I_C = -1\text{ A}$, $I_B = -0.05\text{ Adc}$)	$V_{BE(sat)}$	-	-	-1.2	Vdc
Base-Emitter On Voltage (Note 3) ($I_C = -1\text{ Adc}$, $V_{CE} = -2\text{ Vdc}$)	$V_{BE(on)}$	-	-	-1.2	Vdc

DYNAMIC CHARACTERISTICS

Current-Gain – Bandwidth Product (Note 4) ($I_C = -500\text{ mAdc}$, $V_{CE} = -2\text{ Vdc}$, $f_{test} = 10\text{ MHz}$)	f_T	-	80	-	MHz
Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f = 0.1\text{ MHz}$)	C_{ob}	-	33	-	pF
Switching Timers $V_{CC} = -30\text{ V}$, $I_C = -1\text{ A}$	t_{ON}	-	55	-	ns
	t_{STG}	-	320	-	
	t_f	-	40	-	

3. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\approx 2\%$.

4. $f_T = |h_{fe}| \cdot f_{test}$.

TYPICAL CHARACTERISTICS

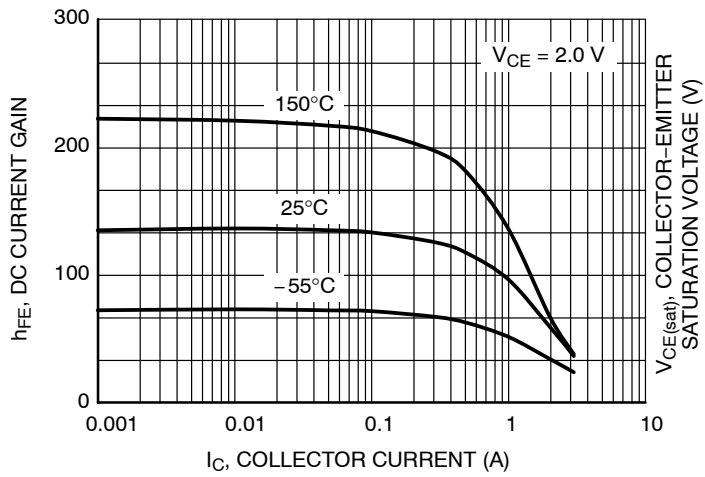


Figure 1. DC Current Gain

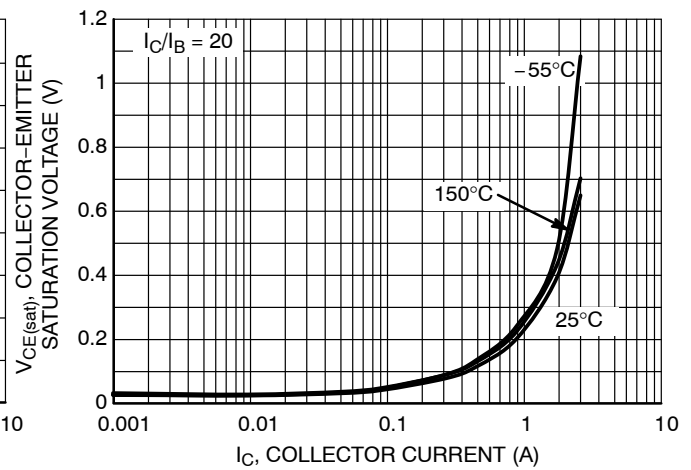


Figure 2. Collector-Emitter Saturation Voltage

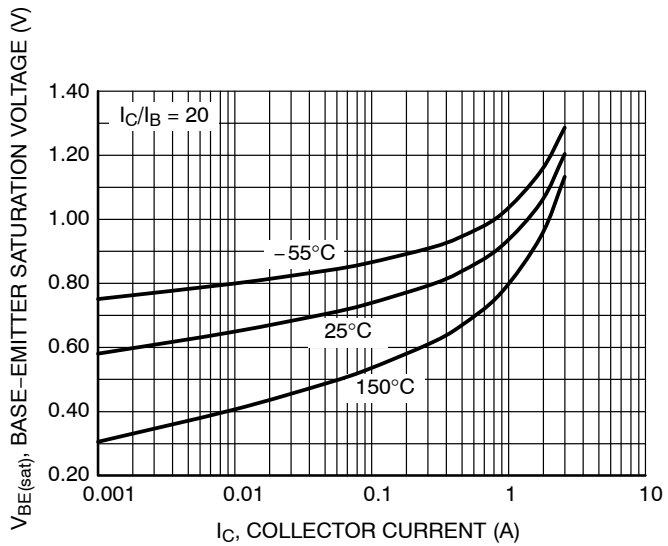


Figure 3. Base-Emitter Saturation Voltage

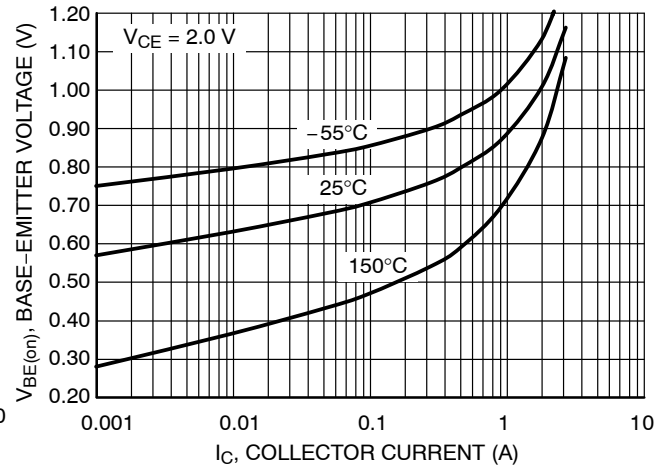


Figure 4. Base-Emitter Voltage

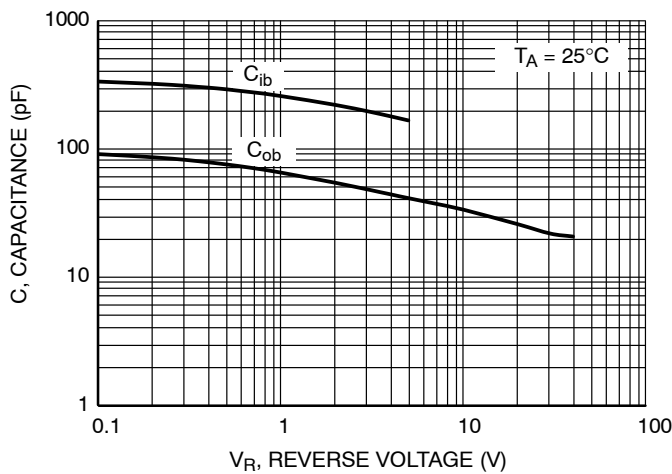


Figure 5. Capacitance

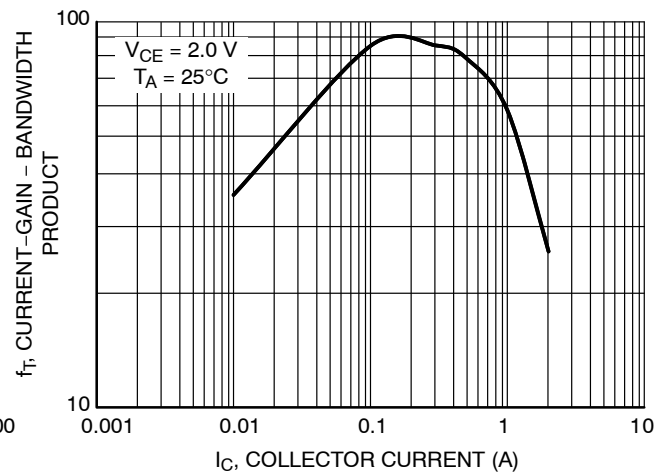


Figure 6. Current-Gain-Bandwidth Product

TYPICAL CHARACTERISTICS

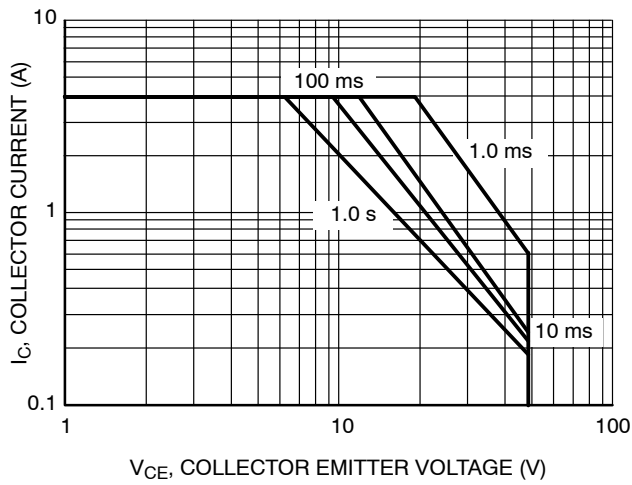


Figure 7. State Operating Area

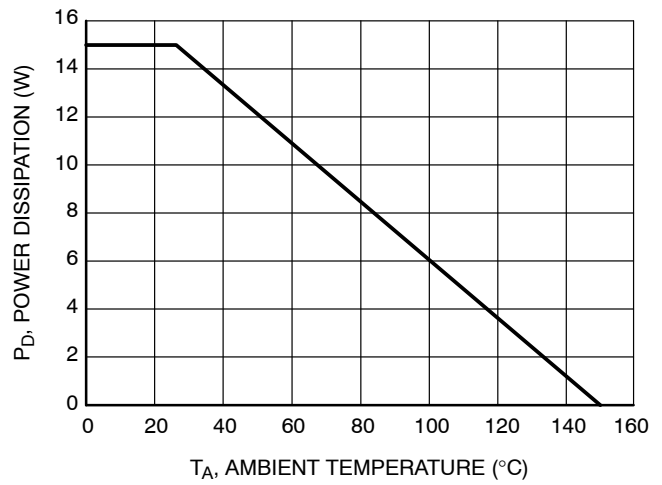


Figure 8. Power Derating

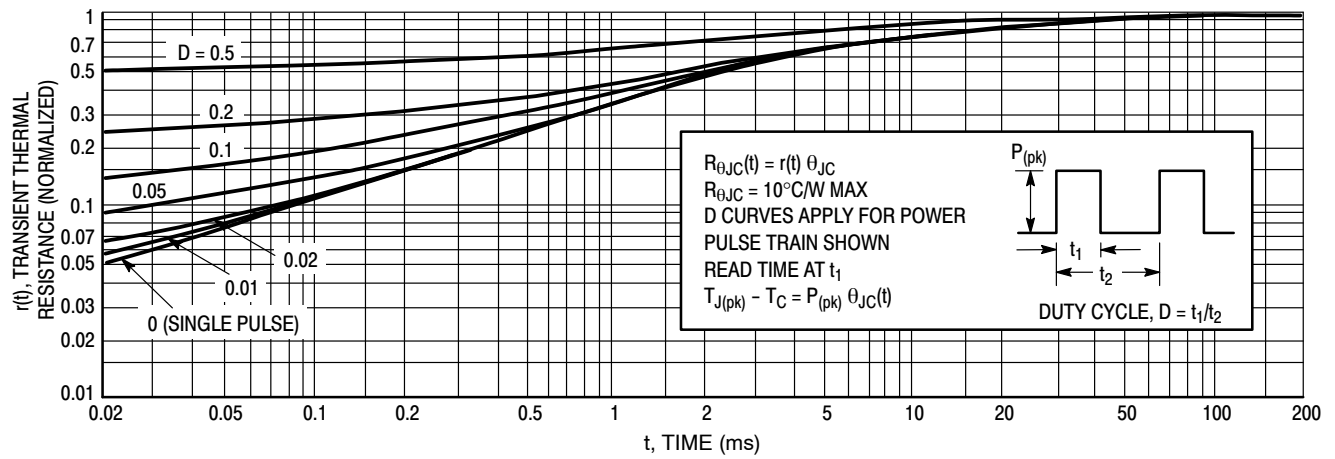
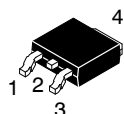


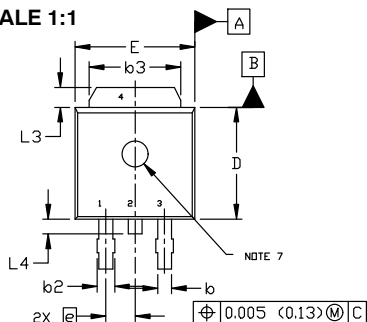
Figure 9. Thermal Response



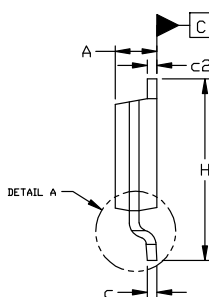
DPAK (SINGLE GAUGE)
CASE 369C
ISSUE G

DATE 31 MAY 2023

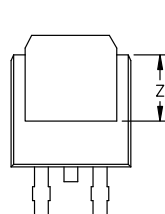
SCALE 1:1



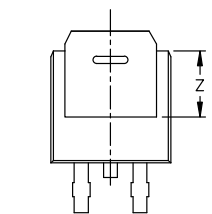
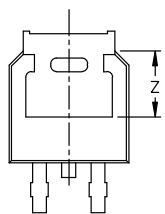
TOP VIEW



SIDE VIEW

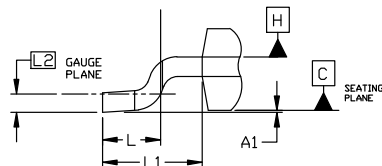
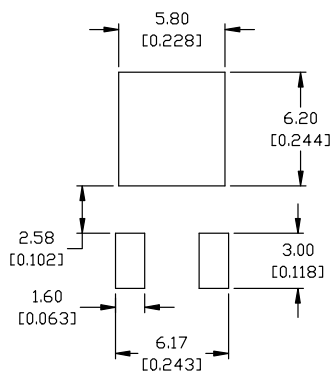


BOTTOM VIEW



BOTTOM VIEW

ALTERNATE
CONSTRUCTIONS



DETAIL A
ROTATED 90° CW

NOTES:

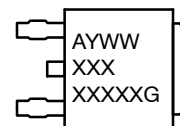
1. DIMENSIONING AND TOLERANCING ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3, AND Z.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
7. OPTIONAL MOLD FEATURE.

DIM	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.028	0.045	0.72	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
e	0.090	BSC	2.29	BSC
H	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.114	REF	2.90	REF
L2	0.020	BSC	0.51	BSC
L3	0.035	0.050	0.89	1.27
L4	----	0.040	---	1.01
Z	0.155	----	3.93	---

GENERIC
MARKING DIAGRAM*



IC



Discrete

XXXXXX = Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
WW = Work Week
G = Pb-Free Package

RECOMMENDED MOUNTING FOOTPRINT*

*FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR	STYLE 2: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN	STYLE 3: PIN 1. ANODE 2. CATHODE 3. ANODE 4. CATHODE	STYLE 4: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE	STYLE 5: PIN 1. GATE 2. ANODE 3. CATHODE 4. ANODE
STYLE 6: PIN 1. MT1 2. MT2 3. GATE 4. MT2	STYLE 7: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR	STYLE 8: PIN 1. N/C 2. CATHODE 3. ANODE 4. CATHODE	STYLE 9: PIN 1. ANODE 2. CATHODE 3. RESISTOR ADJUST 4. CATHODE	STYLE 10: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. ANODE

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	DPAK (SINGLE GAUGE)	PAGE 1 OF 1

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